

SAM™ Data Sheet SAM-1064-40-500fs-x, $\lambda = 1064\text{nm}$

Laser wavelength	$\lambda = 1064\text{ nm}$
High reflection band (R > 54%)	$\lambda = 1000 \dots 1100\text{ nm}$
Absorbance	$A_0 = 40\%$
Modulation depth	$\Delta R = 22\%$
Non-saturable loss	$A_{ns} = 18\%$
Saturation fluence	$\Phi_{sat} = 130\ \mu\text{J}/\text{cm}^2$
Relaxation time constant	$\tau \sim 500\text{ fs}$
Damage threshold	$300\text{ MW}/\text{cm}^2$
Chip area	4mm x 4mm; other dimensions on request
Chip thickness	450 μm
Protection	the SAM is protected with a dielectric front layer

Mounting option **x** denotes the type of mounting as follows:

x = 0	unmounted
x = 12.7 g	glued on a gold plated Cu-cylinder with 12.7 mm \varnothing
x = 25.4 g	glued on a gold plated Cu-cylinder with 25.4 mm \varnothing
x = 12.7 s	soldered on a gold plated Cu-cylinder with 12.7 mm \varnothing
x = 25.4 s	soldered on a gold plated Cu-cylinder with 25.4 mm \varnothing
x = FC	mounted on a 1 m monomode fiber cable with FC connector

Low Intensity Spectral Reflectance

